

TOSHIBA Multi-Chip Device Silicon P-Channel MOS Type + N-Channel MOS Type

## SSM6E03TU

### ○Power Management Switch Applications

- P-channel MOSFET and 1.8 V drive
- N-channel MOSFET and 1.5 V drive
- P-channel MOSFET and N-channel MOSFET incorporated into one package.
- Low power dissipation due to P-channel MOSFET that features low R<sub>DS (ON)</sub> and low-voltage operation

#### Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V <sub>DS</sub>	-20	V
Gate-Source voltage	V <sub>GS</sub>	± 8	V
Drain current	DC	I <sub>D</sub>	-1.8
	Pulse	I <sub>DP</sub> (Note 1)	-3.6

#### Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V <sub>DS</sub>	20	V
Gate-Source voltage	V <sub>GS</sub>	± 10	V
Drain current	DC	I <sub>D</sub>	0.1
	Pulse	I <sub>DP</sub> (Note 1)	0.2

#### Absolute Maximum Ratings (Q1, Q2 common) (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain power dissipation	P <sub>D</sub> (Note 2)	0.5	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

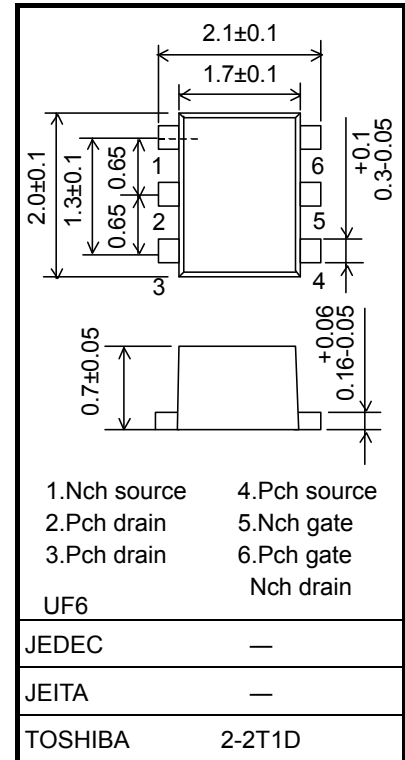
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width limited by maximum channel temperature.

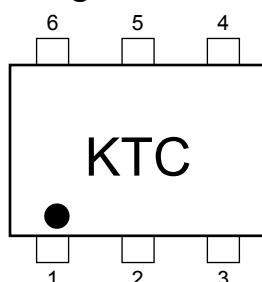
Note 2: Mounted on an FR4 board (25.4 mm × 25.4 mm × 1.6 mm, Cu pad: 645 mm<sup>2</sup>)

Unit: mm

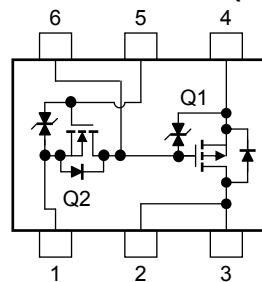


Weight: 7.0 mg (typ.)

#### Marking



#### Equivalent Circuit (top view)



Start of commercial production  
2006-10

## Q1 Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1 \text{ mA}, V_{GS} = 0$	-20	—	—	V	
	$V_{(BR)DSX}$	$I_D = -1 \text{ mA}, V_{GS} = +8 \text{ V}$	-12	—	—		
Drain cutoff current	$I_{DSS}$	$V_{DS} = -20 \text{ V}, V_{GS} = 0$	—	—	-10	$\mu\text{A}$	
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0$	—	—	$\pm 1$	$\mu\text{A}$	
Gate threshold voltage	$V_{th}$	$V_{DS} = -3 \text{ V}, I_D = -1 \text{ mA}$	-0.3	—	-1.0	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 \text{ V}, I_D = -1 \text{ A}$ (Note 3)	1.8	3.7	—	S	
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = -1.0 \text{ A}, V_{GS} = -4 \text{ V}$ (Note 3)	—	105	144	m $\Omega$	
		$I_D = -0.5 \text{ A}, V_{GS} = -2.5 \text{ V}$ (Note 3)	—	138	180		
		$I_D = -0.2 \text{ A}, V_{GS} = -1.8 \text{ V}$ (Note 3)	—	190	335		
Input capacitance	$C_{iss}$	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	335	—	pF	
Output capacitance	$C_{oss}$		—	70	—		
Reverse transfer capacitance	$C_{rss}$		—	56	—		
Switching time	Turn-on time	$t_{on}$	$V_{DD} = -10 \text{ V}, I_D = -1.0 \text{ A},$ $V_{GS} = 0 \text{ to } -2.5 \text{ V}, R_G = 4.7 \Omega$	—	20	—	ns
	Turn-off time	$t_{off}$		—	20	—	
Drain-source forward voltage	$V_{DSF}$	$I_D = 1.8 \text{ A}, V_{GS} = 0$ (Note 3)	—	0.85	1.2	V	

Note 3: Pulse test

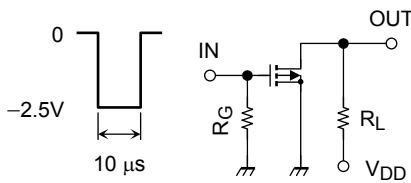
## Q2 Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	20	—	—	V	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	—	—	1	$\mu\text{A}$	
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	—	—	$\pm 1$	$\mu\text{A}$	
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.6	—	1.1	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$ (Note 3)	40	—	—	mS	
Drain-Source on-resistance	$R_{DS(ON)}$	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note 3)	—	1.5	3.0	$\Omega$	
		$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note 3)	—	2.2	4.0		
		$I_D = 1 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note 3)	—	5.2	15		
Input capacitance	$C_{iss}$	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	9.3	—	pF	
Output capacitance	$C_{oss}$		—	9.8	—		
Reverse transfer capacitance	$C_{rss}$		—	4.5	—		
Switching time	Turn-on time	$t_{on}$	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 50 \Omega$	—	70	—	ns
	Turn-off time	$t_{off}$		—	125	—	

Note 3: Pulse test

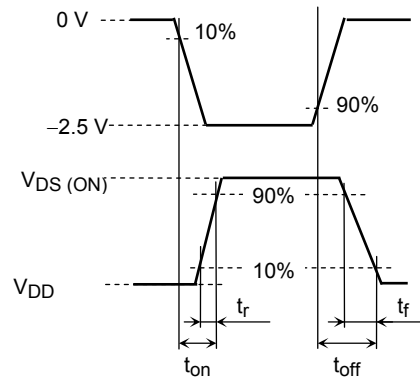
**Switching Time Test Circuit (Q1)**

**(a) Test circuit**



$V_{DD} = -10\text{ V}$   
 $R_G = 4.7\ \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5\text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

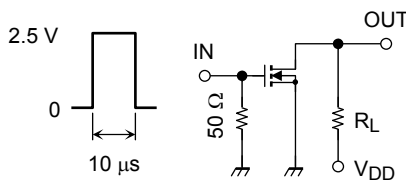
**(b)  $V_{IN}$**



**(c)  $V_{OUT}$**

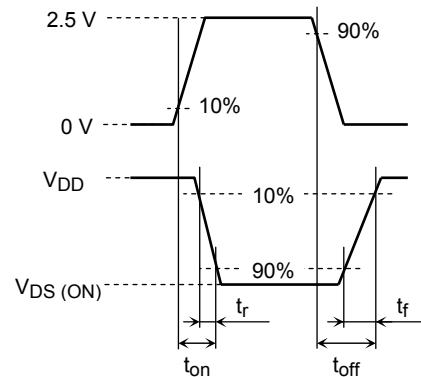
**Switching Time Test Circuit (Q2)**

**(a) Test circuit**



$V_{DD} = 3\text{ V}$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5\text{ ns}$   
 $(Z_{out} = 50\ \Omega)$   
 Common Source  
 $T_a = 25^\circ\text{C}$

**(b)  $V_{IN}$**



**(c)  $V_{OUT}$**

**Precaution(Pch)**

$V_{th}$  can be expressed as the voltage between the gate and source when the low operating current value is  $I_D = -1\text{mA}$  for this product. For normal switching operation,  $V_{GS(on)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(off)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .)

Be sure to take this into consideration when using the device.

**Precaution(Nch)**

$V_{th}$  can be expressed as the voltage between the gate and source when the low operating current value is  $I_D = 0.1\text{mA}$  for this product. For normal switching operation,  $V_{GS(on)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(off)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .)

Be sure to take this into consideration when using the device.

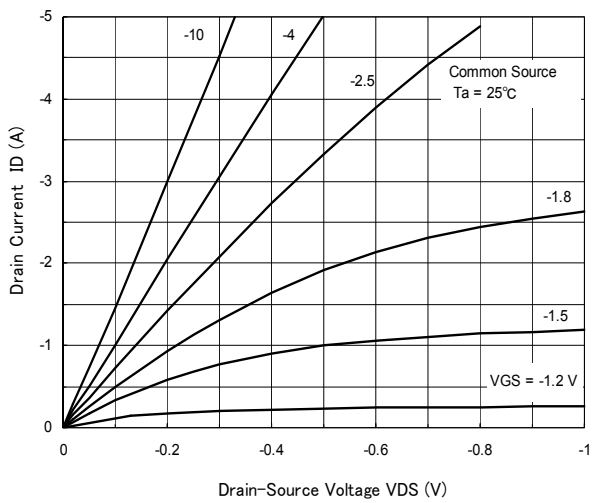
**Handling Precaution**

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

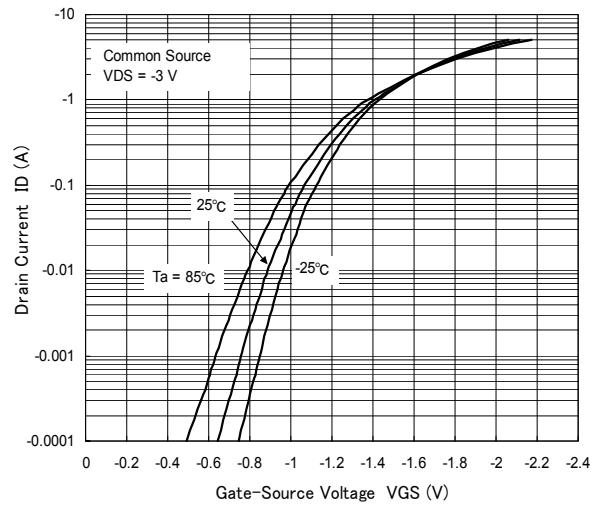
Thermal resistance  $R_{th(j-a)}$  and drain power dissipation  $P_D$  vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

## Q1 (Pch MOSFET)

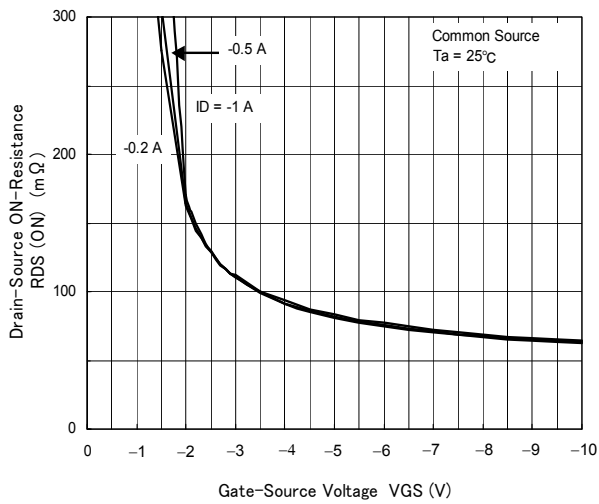
**ID - VDS**



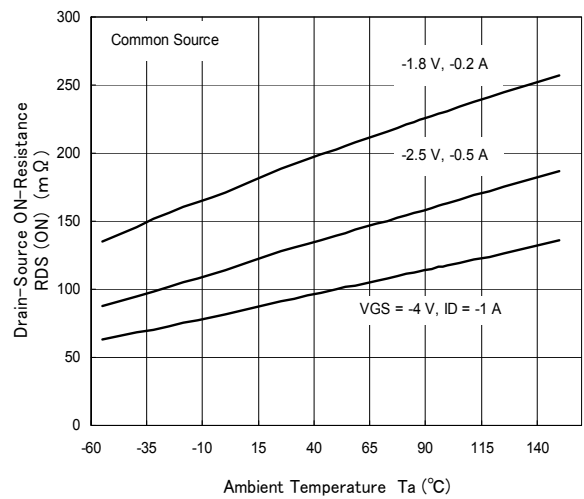
**ID - VGS**



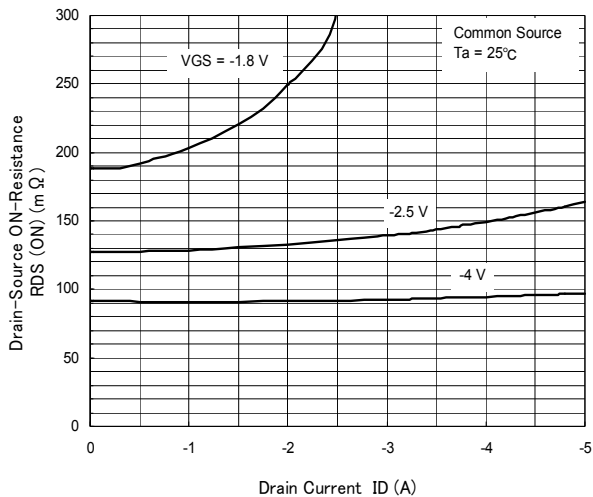
**RDS (ON) - VGS**



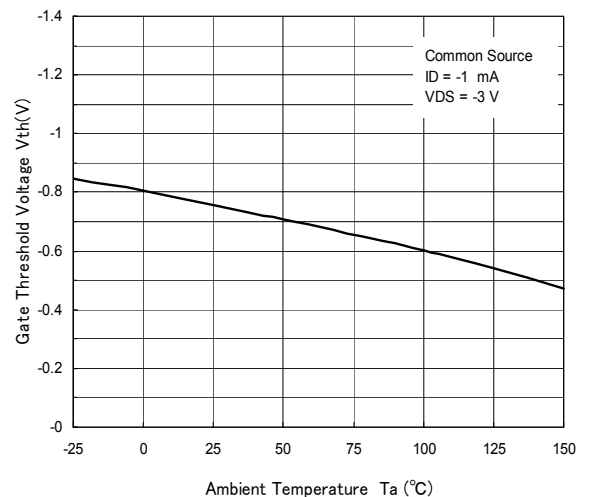
**RDS (ON) - Ta**



**RDS (ON) - ID**

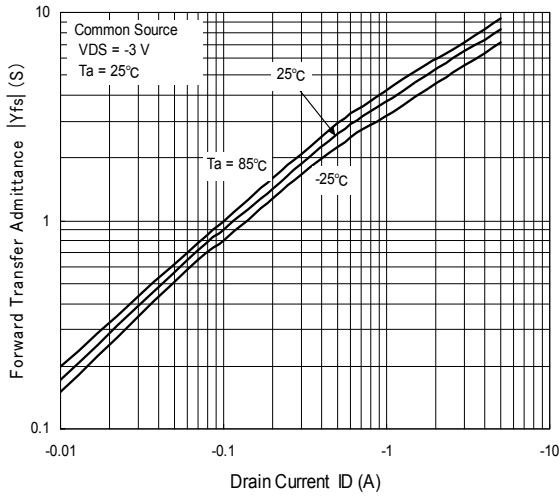


**Vth - Ta**

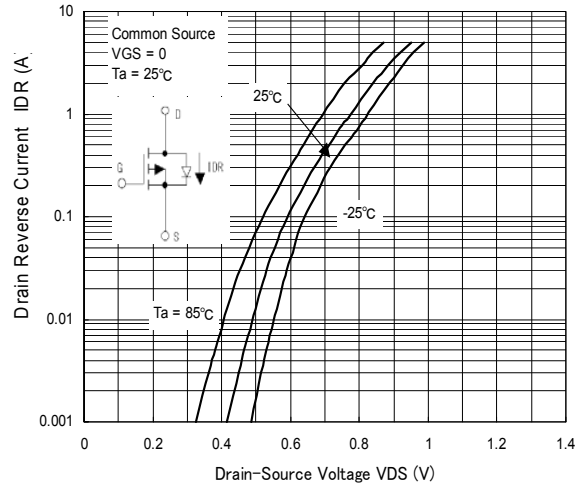


## Q1 (Pch MOSFET)

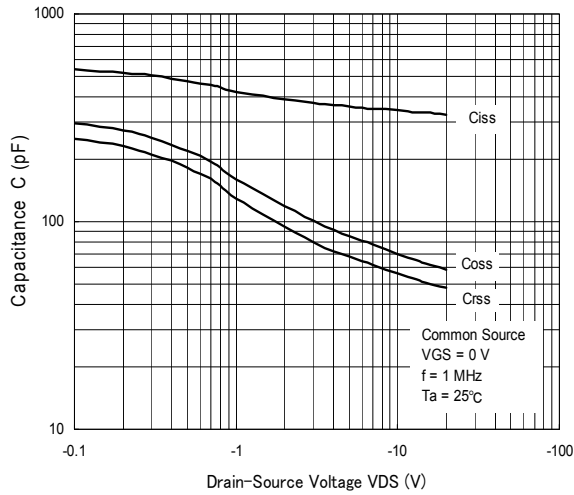
**|Yfs| - ID**



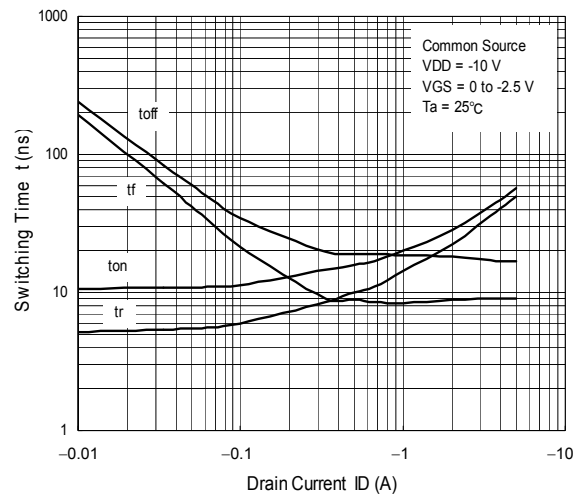
**IDR - VDS**



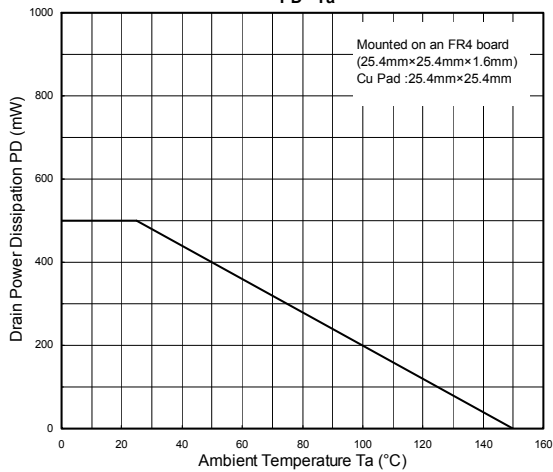
**C - VDS**



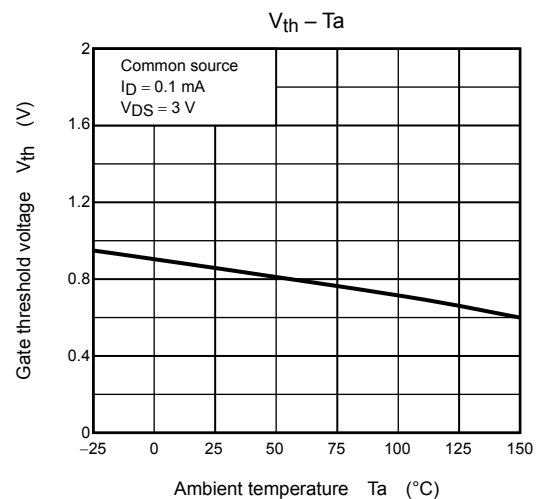
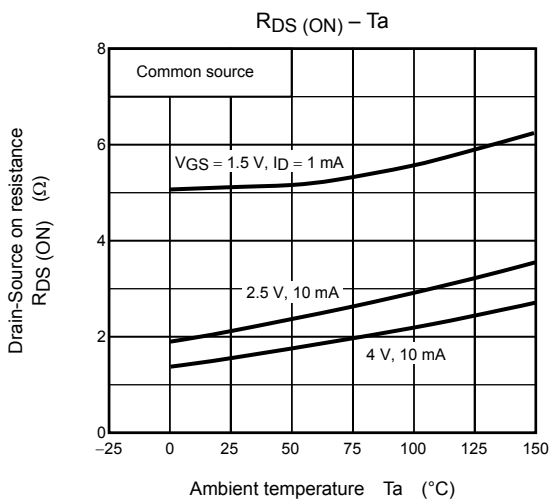
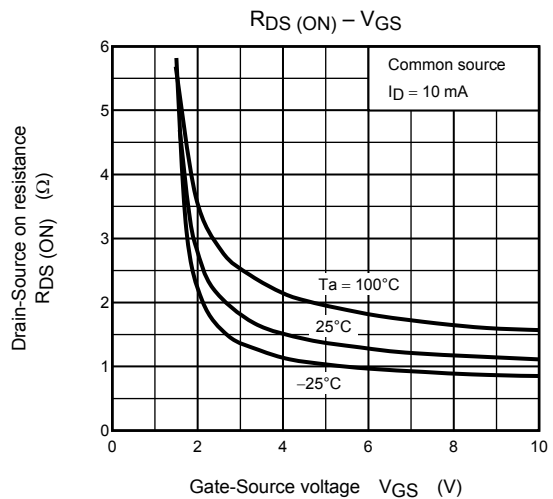
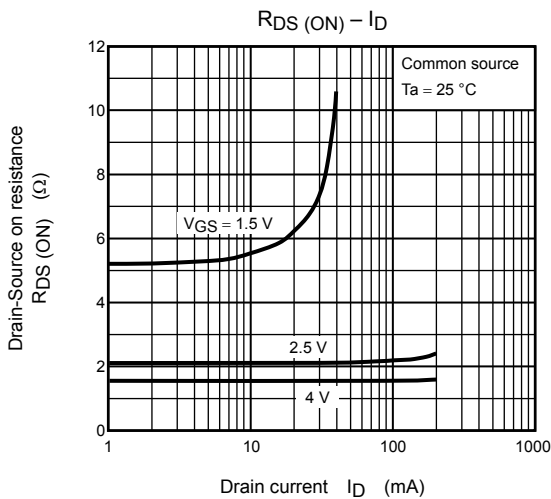
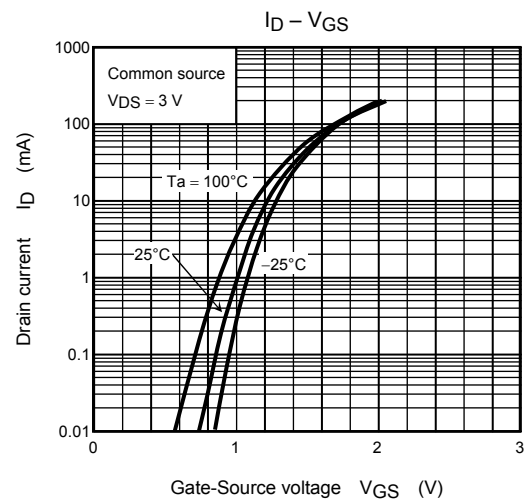
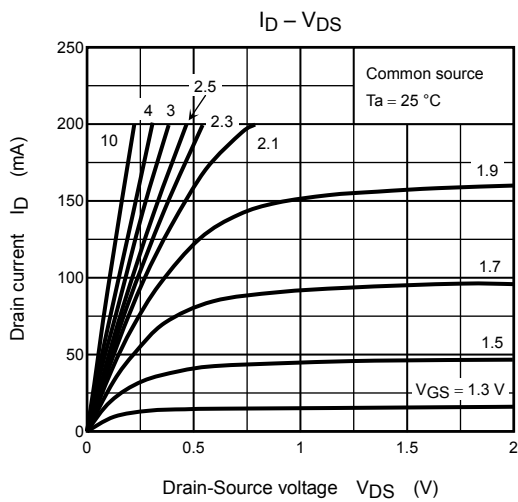
**t - ID**



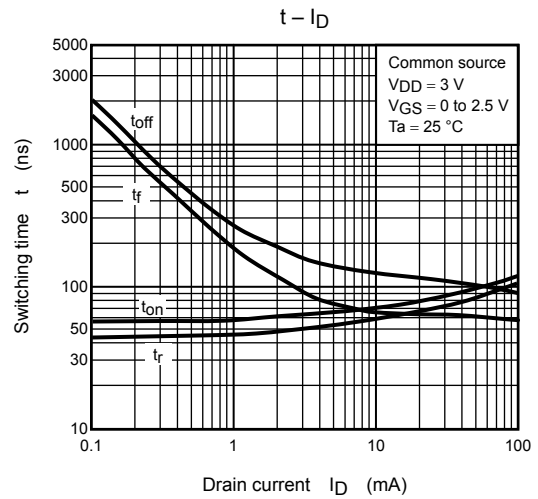
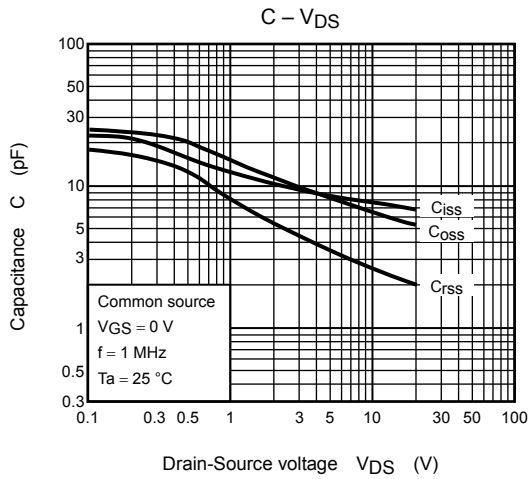
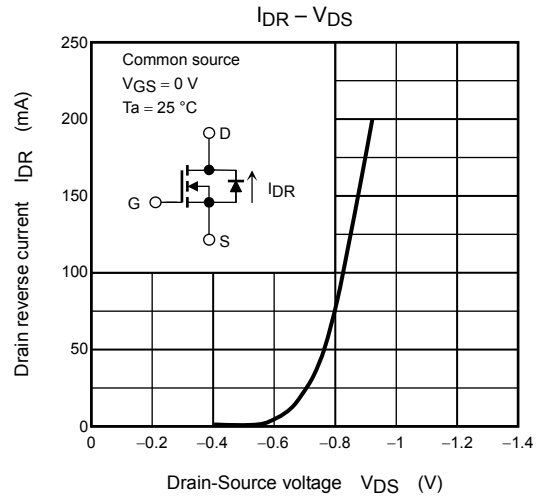
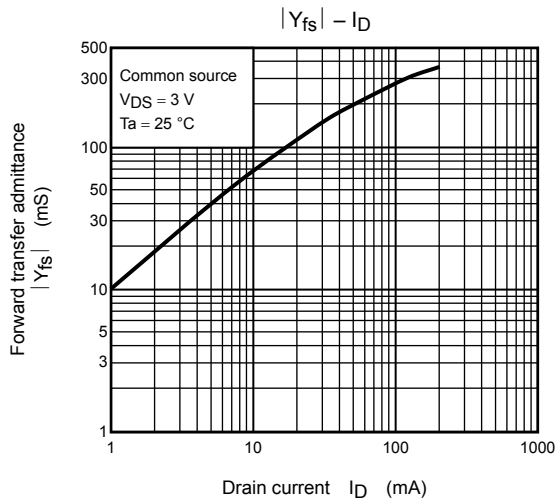
**PD - Ta**



## Q2 (Nch MOSFET)



## Q2 (Nch MOSFET)



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